

IPP80N06S4L05AKSA1

IPP80N06S4L05AKSA1 Information

	Part Number	IPP80N06S4L05AKSA1
-	Manufacturer	Infineon Technologies
www.heiseper.com	Category	Discrete Semiconductor Products Transistors - FETs, MOSFETs - Single
	Description	MOSFET N-CH 60V 80A TO220-3
1	Package	TO-220-3
		For the pricing/inventory/lead time, please contact
For Reference Only		us Website: https://www.heisener.com E-mail: salesdept@heisener.com



Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



IPP80N06S4L05AKSA1 Specifications

Manufacturer Part Number	IPP80N06S4L05AKSA1
Manufacturer	Infineon Technologies
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Single
Package	TO-220-3
Series	OptiMOS?
FET Type	N-Channel
Technology	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss)	60V
Current - Continuous Drain (Id) @ 25°C	80A (Tc)
Drive Voltage (Max Rds On, Min Rds On)	4.5V, 10V
Vgs(th) (Max) @ Id	2.2V @ 60µA
Gate Charge (Qg) (Max) @ Vgs	110nC @ 10V
Input Capacitance (Ciss) (Max) @ Vds	8180pF @ 25V
Vgs (Max)	±16V
FET Feature	-
Power Dissipation (Max)	107W (Tc)
Rds On (Max) @ Id, Vgs	5.1 mOhm @ 80A, 10V
Operating Temperature	-55°C ~ 175°C (TJ)
Mounting Type	Through Hole
Supplier Device Package	PG-TO220-3-1
Package / Case	TO-220-3
	Report errors?

IPP80N06S4L05AKSA1 Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

IPP80N06S4L05AKSA1 Payment Methods





If you have any question about IPP80N06S4L05AKSA1, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com